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HMC345* Product Page Quick Links

Last Content Update: 08/30/2016

Comparable Parts

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Evaluation Kits

• HMC345LP3 Evaluation Board

Documentation 🖵

Data Sheet

• HMC345 Data Sheet

Tools and Simulations

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Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: 16L 3x3mm QFN Package (QTR: 11003 REV: 02)
- Package/Assembly Qualification Test Report: LP2, LP2C, LP3, LP3B, LP3C, LP3D, LP3F, LP3G (QTR: 2014-0364)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: MESFET-F (QTR: 2013-00247)

Design Resources 🖵

- HMC345 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions 🖵

View all HMC345 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

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MICROWAVE CORPORATION v04.0805



HMC345LP3 / 345LP3E

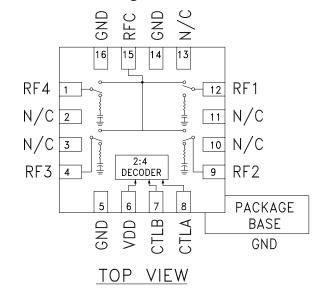
GaAs MMIC SP4T NON-REFLECTIVE POSITIVE CONTROL SWITCH, DC* - 8 GHz

Typical Applications

This switch is suitable for usage in DC - 8.0 GHz 50-Ohm or 75-Ohm systems:

- Broadband
- Fiber Optics
- Switched Filter Banks
- Wireless below 8 GHz

Functional Diagram



Features

Broadband Performance: DC - 8 GHz High Isolation: 35 dB@ 6 GHz Low Insertion Loss: 2.2 dB@ 6 GHz Integrated Positive Supply 2:4 TTL Decoder 3 x 3 mm SMT Package

General Description

The HMC345LP3 & HMC345LP3E are broadband non-reflective GaAs MESFET SP4T switches in low cost leadless surface mount packages. Covering DC to 8 GHz, this switch offers high isolation and low insertion loss. This switch also includes an on board binary decoder circuit which reduces the required logic control lines to two. The switch operates using a positive control voltage of 0/+5V, and requires a fixed bias of +5V.

* Blocking capacitors are required at ports RFC and RF1, 2, 3, & 4. Their value will determine the lowest transmission frequency.

Electrical Specifications, $T_{a} = +25^{\circ}$ C, With 0/+5V Control, 50 Ohm System

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 6.0 GHz DC - 8.0 GHz		2.0 2.2 2.4	2.4 2.6 2.9	dB dB dB
Isolation		DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz DC - 8.0 GHz	37 32 31 27	42 37 35 32		dB dB dB dB
Return Loss	"On State"	DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz DC - 8.0 GHz	10 8 7 6	13 11 10 9		dB dB dB dB
Return Loss (RF1 - RF4)	"Off State"	2.0 - 8.0 GHz	6	10		dB
Input Power for 1 dB Compression		2.0 - 8.0 GHz	17	21		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone, 1MHz Tone Separation)		2.0 - 8.0 GHz	37	45		dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		DC - 8.0 GHz		50 120		ns ns

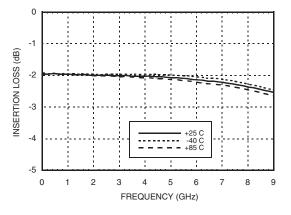
For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com



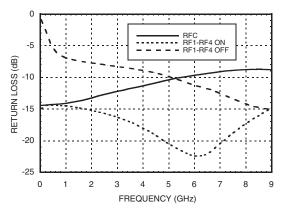


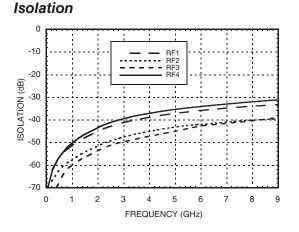
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Insertion Loss vs. Temperature

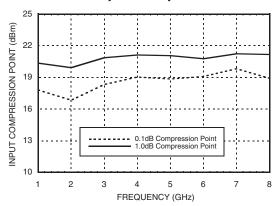


Return Loss

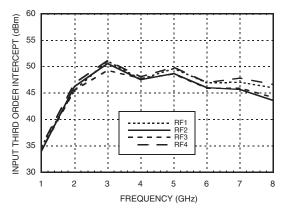




0.1 and 1 dB Input Compression Point







* Isolation is recorded above insertion loss & measured at output of switch.

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Absolute Maximum Ratings

Bias Voltage Range (Vdd)	+7.0 Vdc
Control Voltage Range (A & B)	-0.5V to Vdd +1.0 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	143 °C/W
Thermal Resistance (Terminated Path)	1030 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power	+24 dBm
ESD Sensitivity (HBM)	Class 1A



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Bias Voltage & Current

Vdd Range = +5.0 Vdc ± 10%		
Vdd (Vdc)	ldd (Typ.) (mA)	Idd (Max.) (mA)
+5.0	3.0	6.0

Control Voltages

State	Bias Condition	
Low	0 to +0.8 Vdc @ 5 uA Typical	
High +2.0 to +5.0 Vdc @ 60 uA Typical		

Truth Table

Control Input		Signal Path State
А	В	RFCOM to:
Low	Low	RF1
High	Low	RF2
Low	High	RF3
High	High	RF4

Note: DC blocking capacitors are required at ports RFC and RF1, 2, 3, & 4. Their value will determine the lowest transmission frequency.

Order On-line at www.hittite.com

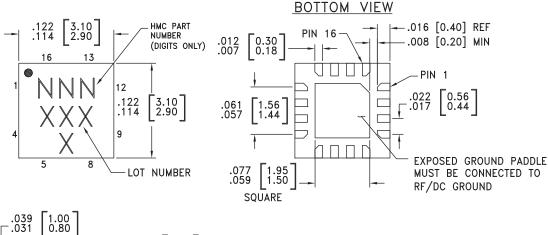
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ROHS V EARTH FRIENDLY

GaAs MMIC SP4T NON-REFLECTIVE POSITIVE CONTROL SWITCH, DC* - 8 GHz

Outline Drawing



-C-

NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM. 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE
- SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

⊇ .003[0.08] C

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC345LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	345 XXXX
HMC345LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>345</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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Pin Descriptions

Pin Number	Function	Description	Interface Schematic	
1, 4, 9, 12, 15	RF4, RF3, RF2, RF1, RFC	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required.		
2, 3, 10, 11, 13	N/C	This pin should be connected to PCB RF ground to maximize isolation.		
5, 14, 16	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.		
6	VDD	Supply Voltage +5V ± 10%	VddO	
7	CTLB	See truth table and control voltage table.	OVdd	
8	CTLA	See truth table and control voltage table.		

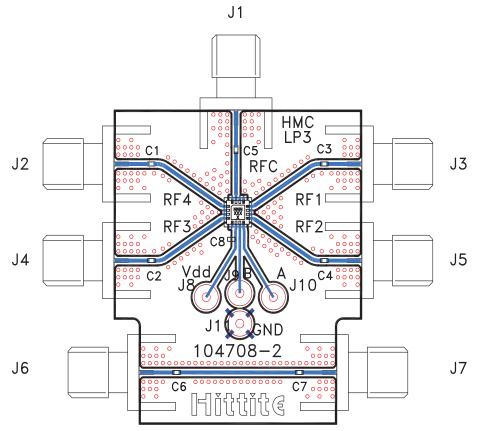


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Evaluation PCB



MITCHE

List of Materials for Evaluation PCB 108333^[1]

Item	Description	
J1 - J7	PCB Mount SMA RF Connector	
J8 - J11	DC Pin	
C1 - C7	100 pF Capacitor, 0402 Pkg.	
C8	10k pF Capacitor, 0603 Pkg.	
U1	HMC345LP3 / HMC345LP3E SP4T Switch	
PCB [2]	104708 Evaluation PCB 1.29"x1.55"	

Reference this number when ordering complete evaluation PCB
 Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.